Power MOSFET

-12 V, -5.3 A, Single P-Channel, TSOP-6

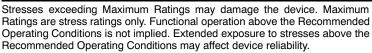
Features

- Low R_{DS(on)} in TSOP-6 Package
- 1.8 V Gate Rating
- This is a Pb-Free Device

Applications

- Battery Switch and Load Management Applications in Portable Equipment
- High Side Load Switch
- PA Switch

MAXIMUM RATINGS (T _J = 25° C unless otherwise stated)							
Paran	Symbol	Value	Unit				
Drain-to-Source Voltage			V _{DSS}	-12	V		
Gate-to-Source Voltage			V _{GS}	±8	V		
Continuous Drain	Steady	T _A = 25°C	I _D	-4.7	А		
Current (Note 1)	State	T _A = 85°C	1	-3.4			
	$t \le 5 s$	T _A = 25°C	1	-5.3			
Power Dissipation (Note 1)	Steady State	T _A = 25°C	P _D	1.25	W		
	$t \le 5 s$			1.6			
Continuous Drain	Steady	T _A = 25°C	I _D	-3.4	А		
Current (Note 2)	State	T _A = 85°C	1	-2.5			
Power Dissipation (Note 2)		T _A = 25°C	P _D	0.7	W		
Pulsed Drain Current	t _p = 10 μs		I _{DM}	-19	А		
Operating Junction and Storage Temperature			T _J , T _{STG}	-55 to 150	°C		
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C		
Lead Temperature for Soldering Purposes			T _{STG} TL	150 260	°C		



1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces)

2. Surface-mounted on FR4 board using the minimum recommended pad size.

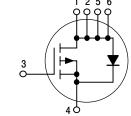


ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
-12 V	40 mΩ @ -4.5 V	-4.7 A
	53 mΩ @ −2.5 V	-4.1 A
	72 mΩ @ -1.8 V	-2.0 A









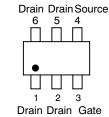
SE = Device Code Μ

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT



ORDERING INFORMATION

Device	Package	Shipping [†]
NTGS3447PT1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{ hetaJA}$	100	
Junction-to-Ambient – t \leq 5 s (Note 3)	$R_{ hetaJA}$	78	°C/W
Junction-to-Ambient – Minimum Pad (Note 4)	$R_{ hetaJA}$	188	

Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces)
Surface-mounted on FR4 board using the minimum recommended pad size (Cu area = 0.0775 in sq).

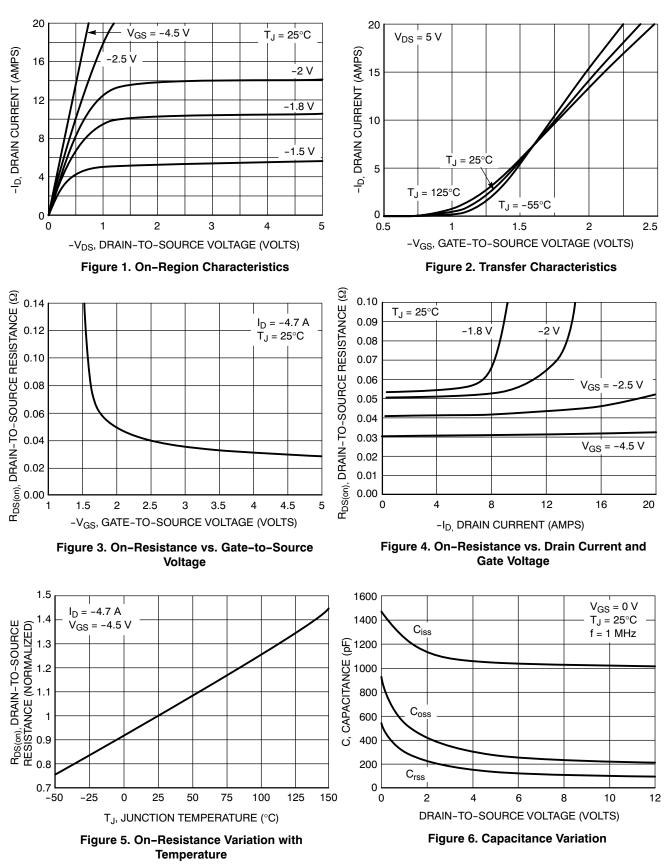
ELECTRICAL CHARACTERISTICS (T₁ = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = -250 μ A		-12			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V, V_{DS} = -12 V $ $T_{J} = 25^{\circ}C $ $T_{J} = 85^{\circ}C$	T _J = 25°C			-1.0	μΑ
					-5.0		
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _C	_{as} = ±8 V			±0.1	μΑ
ON CHARACTERISTICS (Note 5)							-
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D$	= -250 μA	-0.45		-1.0	V
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = -4.5 V, I _D = -4.7 A			30	40	mΩ
		V _{GS} = -2.5 V, I _D = -4.1 A			40	53	
		V_{GS} = -1.8 V, I _D = -2.0 A			53	72	
Forward Transconductance	9 _{FS}	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -4.7 \text{ A}$			12		S
CHARGES, CAPACITANCES AND GATE F	ESISTANCE						-
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = -6 V			1053		pF
Output Capacitance	C _{OSS}				254		
Reverse Transfer Capacitance	C _{RSS}				129		
Total Gate Charge	Q _{G(TOT)}				10.4	15	nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = -4.5 V, \ I _D = -4.	/ _{DS} = -6 V;		1.0		-
Gate-to-Source Charge	Q _{GS}	I _D = -4.	7 Å		1.7		
Gate-to-Drain Charge	Q _{GD}	1			0.4		
SWITCHING CHARACTERISTICS, V_{GS} = 4	.5 V (Note 6)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = -4.5 V, V_{DS} = -6 V, I _D = -1.0 A, R _G = 6.0 Ω			7	11	ns
Rise Time	t _r				14	22	
Turn-Off Delay Time	t _{d(OFF)}				78	117	
Fall Time	t _f	1		47	71		

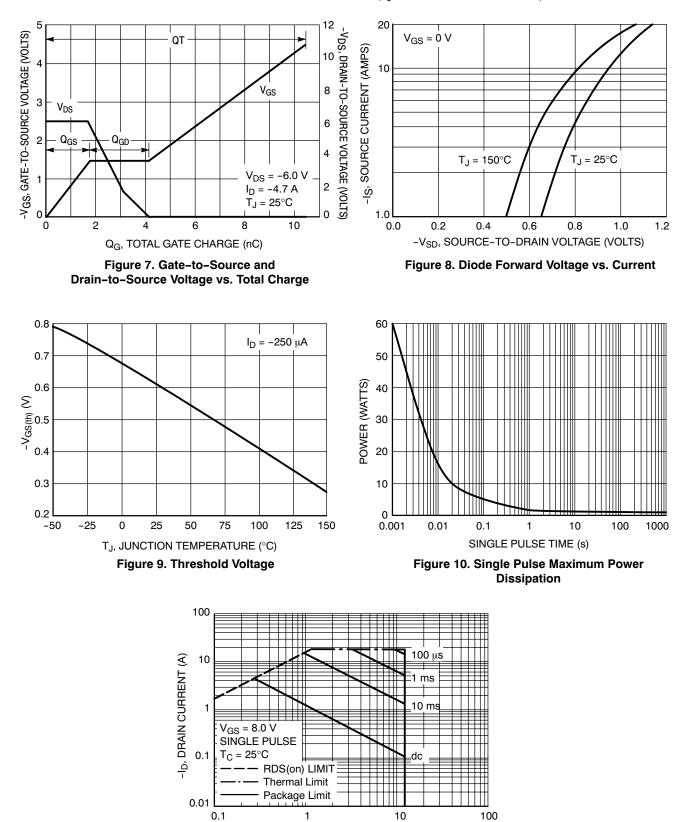
DRAIN-SOURCE DIODE CHARACTERISTICS

Forward Diode Voltage	V_{SD}	V _{GS} = 0 V, I _S = -1.7 A	T _J = 25°C	-0.7	-1.2	V
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V}, \text{ dI}_{SD}/\text{d}_t$ $I_S = -1.7$		33	66	ns

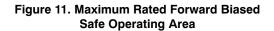
5. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2% 6. Switching characteristics are independent of operating junction temperatures



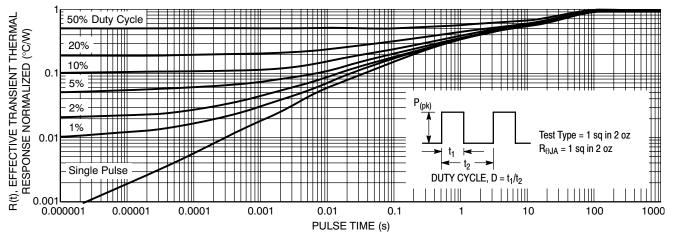
TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)



TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise noted)

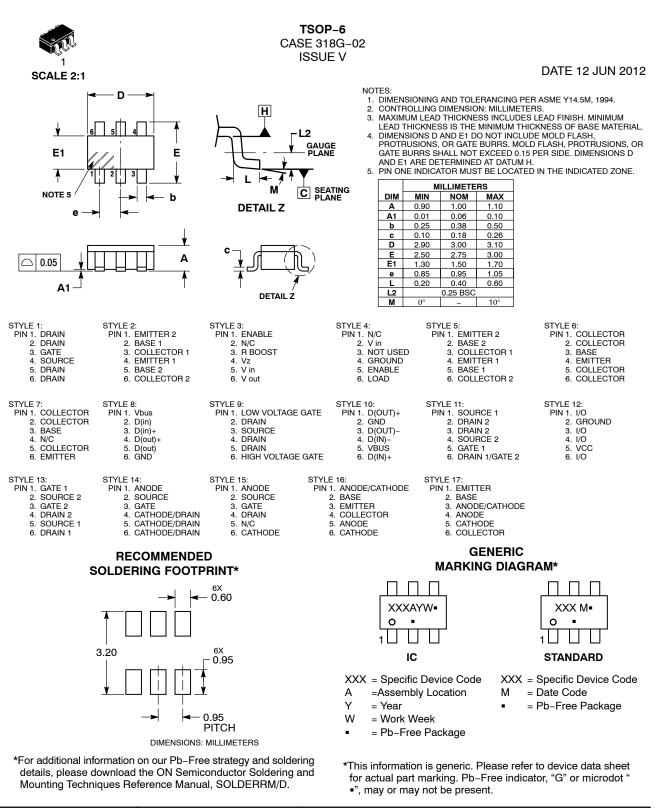


-V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V)









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TSOP-6		PAGE 1 OF 1		
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